



Low Power Schottky Logic – 54LS04

Hex Inverter Gates Logic IC in bare die form

Rev 1.0
24/11/17

Description

The 54LS04 Hex Inverter is fabricated using a 2µm 40V Bipolar process. The device contains six independent inverters with standard push-pull outputs which perform the Boolean function $Y = \bar{A}$ in positive logic. The device is fully characterised over the Military Temperature Range.

Features:

- High speed – 19ns (Typ) propagation delay
- Full Military Temperature Range.
- Direct drop-in replacement for obsolete components in long term programs.

Ordering Information

The following part suffixes apply:

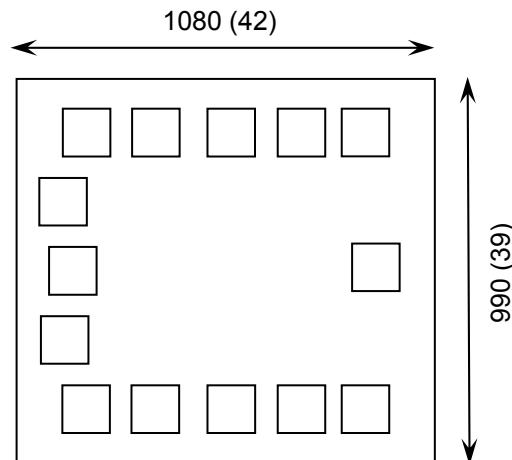
- No suffix - MIL-STD-883 /2010B Visual Inspection
- “H” - MIL-STD-883 /2010B Visual Inspection + MIL-PRF-38534 Class H LAT
- “K” - MIL-STD-883 /2010A Visual Inspection (Space) + MIL-PRF-38534 Class K LAT

LAT = Lot Acceptance Test.

For further information on LAT process flows see below.

www.siliconsupplies.com/quality/bare-die-lot-qualification

Die Dimensions in µm (mils)



Supply Formats:

- Default – Die in Waffle Pack (400 per tray capacity)
- Sawn Wafer on Tape – On request
- Unsawn Wafer – On request
- Die Thickness <> 350µm(14 Mils) – On request
- Assembled into Ceramic Package – On request

Mechanical Specification

Die Size (Unsawn)	1080 x 990 42 x 39	µm mils
Minimum Bond Pad Size	116 x 116 4.6 x 4.6	µm mils
Die Thickness	350 (± 20) 13.78 (± 0.79)	µm mils
Top Metal Composition	Al 1%Si 1.1µm	
Back Metal Composition	N/A – Bare Si	



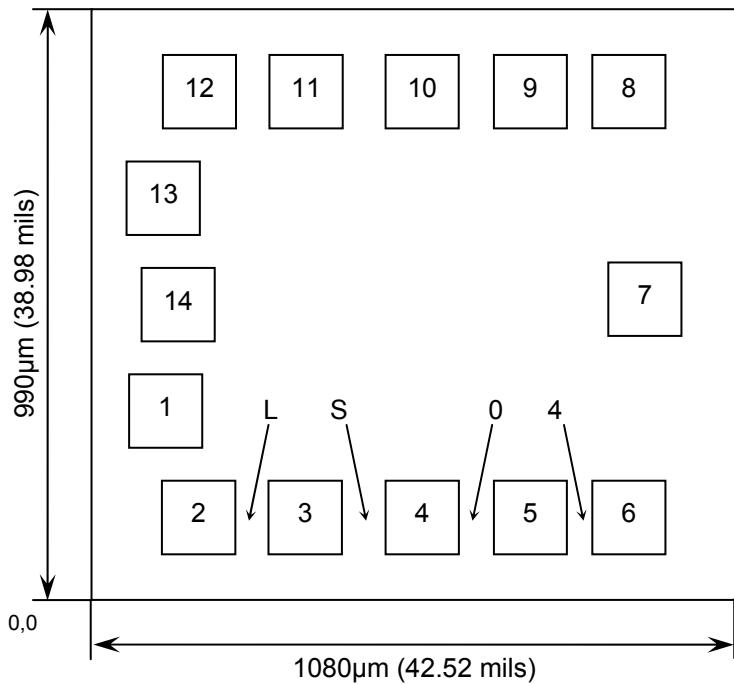


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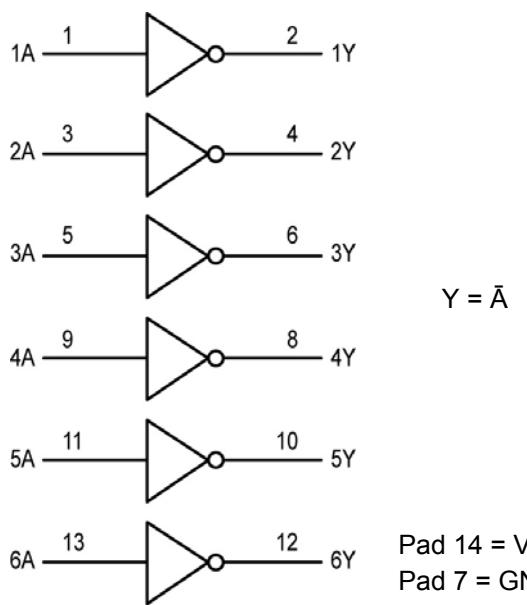
Pad Layout and Functions



PAD	FUNCTION	COORDINATES (mm)	
		X	Y
1	1A	0.073	0.268
2	1Y	0.132	0.092
3	2A	0.308	0.092
4	2Y	0.503	0.092
5	3A	0.685	0.092
6	3Y	0.854	0.092
7	GND	0.880	0.456
8	4Y	0.854	0.804
9	4A	0.685	0.804
10	Y5	0.503	0.804
11	5A	0.308	0.804
12	6Y	0.132	0.804
13	6A	0.073	0.628
14	V _{CC}	0.094	0.450

CONNECT CHIP BACK TO GND OR FLOAT

Logic Diagram



Truth Table

INPUTS	OUTPUT
A	
H L	L H

H = High level (steady state)
L = Low level (steady state)





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Absolute Maximum Ratings¹

PARAMETER	SYMBOL	VALUE	UNIT
DC Supply Voltage	V _{CC}	7.0	V
DC Input Voltage	V _{IN}	7.0	V
Storage Temperature Range	T _{STG}	-65 to 150	°C

1. Operation above the absolute maximum rating may cause device failure. Operation at the absolute maximum ratings, for extended periods, may reduce device reliability.

Recommended Operating Conditions

PARAMETER	SYMBOL	MIN	MAX	UNITS
Supply Voltage	V _{CC}	4.5	5.5	V
High-Level Input Voltage	V _{IH}	2	-	V
Low-Level Input Voltage	V _{IL}	-	0.7	V
High-Level Output Current	I _{OH}	-	-0.4	mA
Low-Level Output Current	I _{OL}	-	4	mA
Operating Temperature Range	T _J	-55	+125	°C

DC Electrical Characteristics² T_J = -55°C to 125°C unless otherwise specified

PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
Minimum High-Level Input Voltage	V _{IH}	-	2	-	-	V
Maximum Low-Level Input Voltage	V _{IL}	-	-	-	0.7	V
Input Clamp Diode Voltage	V _{IK}	V _{CC} = MIN I _{IN} = -18mA	-	-0.65	-1.5	V
Output Voltage High	V _{OH}	V _{CC} = MIN, I _{OH} = MAX V _{IN} = V _{IL} or V _{IH} per Truth Table	2.5	3.4	-	V
Output Voltage Low	V _{OL}	V _{CC} = V _{CC} MIN I _{OH} = MAX V _{IN} = V _{IL} or V _{IH} per Truth Table	-	0.25	0.4	V
Input High Current	I _{IH}	V _{CC} = MAX, V _{IN} = 2.7V V _{CC} = MAX, V _{IN} = 7.0V	-	-	20	µA
Input Low Current	I _{IL}	V _{CC} = MAX, V _{IN} = 0.4V	-	-	0.1	mA
Short Circuit Current ³	I _{OS}	V _{CC} = MAX	-20	-	-100	mA
Power Supply Current (Total)	I _{CC}	V _{CC} = MAX ,Output High V _{CC} = MAX ,Output Low	-	1.2 3.6	2.4 6.6	mA

2. All typical values @ V_{CC} = 5V, T_J = 25°C. 3. Not more than one output should be shorted at a time, nor for more than 1 second.





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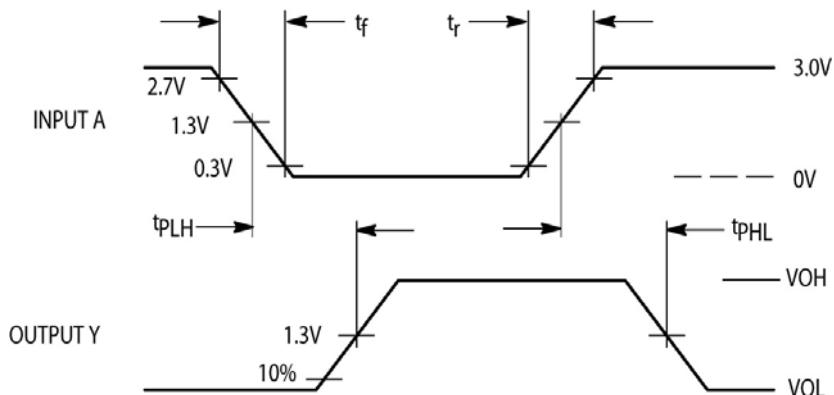
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AC Electrical Characteristics⁴

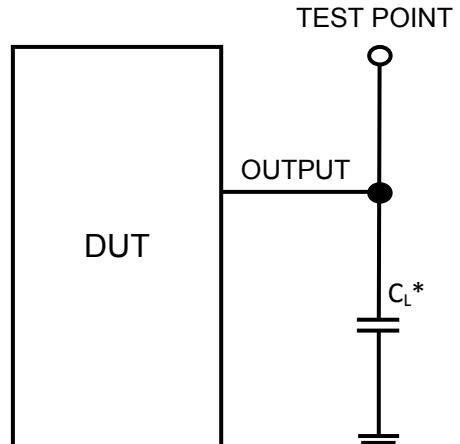
PARAMETER	SYMBOL	CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
Turn-Off Delay, Input to Output	t_{PLH}	$V_{CC} = 5V, C_L = 15pF$	-	9.0	15	ns
Turn-On Delay, Input to Output	t_{PHL}	$V_{CC} = 5V, C_L = 15pF$	-	10	15	

4. Not production tested in die form, characterized by chip design and tested in package.

Switching Waveform



Test Circuit



* Includes all probe and jig capacitance

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